20 STERN AVE. SPRINGFIELD, NEW JERSEY 07081 U.S.A.

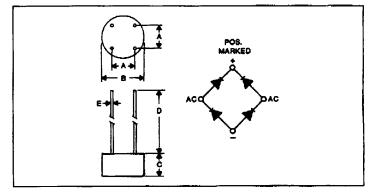
**VE08X – VE106X** 

TELEPHONE: (973) 376-2922 (212) 227-6005 FAX: (973) 376-8960

## 1 Amp Fast Recovery Time Epoxy Bridge Rectifiers

200 Nanosecond Reverse Recovery Time 50V, 100V, 200V, 400V, and 600V  $V_{\text{RRM}}$  Ratings Glass Passivated Silicon Chips

LTR	INCHES	MILLIMETERS
A	.185215	4,70-5,46
в	.350365	8,89-9,27
BC	.190215	4,83-5,46
D	1.0 MIN.	25,4 MIN.
E	.022028 DIA.	,558-,711



## **MAXIMUM RATINGS** (At $T_A = 25^{\circ}$ C unless otherwise noted)

RATINGS	SYMBOL	VE08X	VE18X	VE28X	VE48X	VE68X	VE86X	VE108X	UNITS
DC Blocking Voltage, Working Peak Reverse Voltage, Peak Repetitive Reverse Voltage,	V <sub>RM</sub> V <sub>RMM</sub> V <sub>RMM</sub>	50	100	200	400	600	800	1000	Volts
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	Volts
Peak Surge Current, $\frac{1}{2}$ Cycle at 60 Hz, (Non-Rep) and T <sub>A</sub> = 40°C (Fig.2)	I <sub>FSM</sub>	17							Amps
Peak Surge Current, 1 sec. at 60 Hz and $T_A = 40^{\circ}$ C (Fig. 2)	IFRM	Іглы З							Amps
Avg. Forward Current at Tc = 40°C, (Fig. 1)	la 1					Amps			
Junction Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	- 50 to + 135							°.
Max. Soldering Temperature & Time	10 Sec. at 265°C								

ELECTRICAL CHARACTERISTICS (At T<sub>A</sub> = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL			UNITS
Maximum Instantaneous Forward Voltage Drop (per diode) at 1 Amp (Fig. 3)	V <sub>PM</sub>	1.5	1.6	Volts/ Leg
Maximum Reverse Recovery Time $I_F = 1$ Amp, $I_R = 2$ Amp, $I_{RR} = 0.5$ Amp	t.	200		nsec
Maximum Reverse Current at Rated V <sub>RM</sub>	IRM	10	-	μΑ
Maximum Reverse Current at Rated $V_{RM}$ at $T_A = 125^{\circ}C$ (Fig. 4)	i <sub>nu</sub>	2		mA
Insulation Strength Circuit to Case (Min.)		2000		Vdc
Thermal Resistance (Typ) Junction To Ambient	R <sub>M</sub>	45		•C/W

VE Series Bridges have been recognized under the components program of Underwriters Laboratones, Inc.



NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

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